EAST Search History

EAST Search History (Prior Art)

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|--|---|---------------------|---------|---------------------|
| L2 | 65 | (large or big) near3 (void or hole or empty or null) same (fluorocarbon or fluoro carbon) | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:43 |
| L3 | 0 | (first and second) adj3 (carbon floride) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:44 |
| L4 | 0 | (first and second) near3 (carbon floride) | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:45 |
| L5 | 192 | (first and second) same (carbon fluoride) | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:46 |
| L6 | 11 | (first and second) near3 (carbon fluoride) | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:46 |
| L7 | 1 | L2 and L5 | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:47 |
| L8 | 1 | 12 and L6 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:47 |
| L9 | 14 | ((carbon near3 fluorocarbon) adj3 (film or gas or layer)) near5 (substrate or wafer or semiconductor) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:49 |

| L10 | 0 | L9 and L6 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:49 |
|-----|-------|---|---|-----|----|---------------------|
| L11 | 0 | L9 and L2 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:49 |
| L12 | 32633 | (fluoride or fluor\$3 or fluorocarbon or fluoro-carbon or carbon) near5 (film or layer or dielectric or di-electric or di electric) same (void or space or hole or well) | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:50 |
| L13 | 5 | L9 and L12 | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:50 |
| L14 | 28 | L5 and L12 | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:50 |
| L15 | 4 | L6 and L12 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:51 |
| L16 | 1 | (first and second) near3 (carbon fluoride) adj gas same (substrate or wafer) | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:52 |
| L17 | 1 | (first and second) near3 (carbon fluoride) adj5 gas same (substrate or wafer) | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:53 |
| L18 | 1 | (first and second) adj3 ((carbon fluoride) adj5 gas) same (substrate or wafer) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:54 |

| L19 | 28 | L2 and L12 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 00:59 |
|-----|-------|---|---|-----|----|---------------------|
| L20 | 1 | L14 and L19 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/09/14 01:00 |
| S2 | 0 | JP10-092804A | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/01 13:16 |
| S3 | 0 | JP 10-092804A | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/01 13:16 |
| S4 | 0 | "092804".pn. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/01 13:17 |
| S5 | 1 | "6524963".PN. | US-PGPUB; USPAT; USOCR | ADJ | ON | 2009/04/01 13:17 |
| S6 | 1 | "20070020951".PN. | US-PGPUB; USPAT; USOOR | ADJ | ON | 2009/04/01 13:23 |
| S7 | 2440 | (first or second or third) near3 (fluoride or fluor\$3 or fluorocarbon or fluoro-carbon or carbon) near5 (substrate or wafer or semiconductor) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/01 13:39 |
| S8 | 31130 | (fluoride or fluor\$3 or fluorocarbon or fluoro-carbon or carbon) near5 (film or layer or dielectric or di-electric or di electric) same (void or space or hole or well) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/01 13:41 |
| S10 | 2440 | (first or second or third) near3 (fluoride or fluor\$3 or fluorocarbon or fluoro-carbon or carbon) near5 (substrate or wafer or semiconductor) | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM TDB | ADJ | ON | 2009/04/01 20:13 |

| S11 | 31130 | (fluoride or fluor\$3 or fluorocarbon or fluoro-carbon or carbon) near5 (film or layer or dielectric or di-electric or di electric) same (void or space or hole or well) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/01 20:13 |
|-----|----------|---|---|-----|----|---------------------|
| S12 | 579 | S10 and S11 | US-PGPUB; USPAT; USOCR | OR | ON | 2009/04/01 20:13 |
| S13 | 0 | (first or second or third) near3 ((carbon adj3 fluorocarbon) adj3 (film or gas or layer)) near5 (substrate or wafer or semiconductor) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/01 20:16 |
| S14 | 2 | (first or second or third) near3 (carbon adj3 fluorocarbon) adj3 (film or gas or layer) same (substrate or wafer or semiconductor) | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/01 20:16 |
| S15 | 29211053 | @ad<"20040722" or @rlad<"20040722" | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/01 20:18 |
| S16 | 447 | S12 and S15 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/01 20:19 |
| S17 | 14 | ((carbon near3 fluorocarbon) adj3 (film or gas or layer)) near5 (substrate or wafer or semiconductor) | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/01 20:21 |
| S18 | 13 | S17 and S15 | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/01 20:21 |
| S19 | 1 | (first or second or third) near3 ((carbon adj3 fluorocarbon) adj3 (film or gas or layer)) near5 (void or hole or space) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/01 20:37 |
| S20 | 2 | ("6531409" "6419985").PN. | US-PGPUB; USPAT; USOOR | OR | ON | 2009/04/02 11:54 |

| S21 | 11596 | (remov\$3 or cut\$3 or etch\$3) near3 (volatil\$3 or explosiv\$3 or unstabl\$3) same (carbon or fluorine or fluorocarbon or fluoride) | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/02 11:58 |
|-----|----------|---|---|-----|----|---------------------|
| S22 | 902 | (remov\$3 or cut\$3 or etch\$3) near3 (volatil\$3 or explosiv\$3 or unstabl\$3) same (carbon or fluorine or fluorocarbon or fluoride) with (void or vacuum or space or hole or well) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/02 11:59 |
| S23 | 29211485 | @ad<"20040722" or @rlad<"20040722" | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/02 11:59 |
| S24 | 2442 | (first or second or third) near3 (fluoride or fluor\$3 or fluorocarbon or fluoro-carbon or carbon) near5 (substrate or wafer or semiconductor) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/02 12:01 |
| S25 | 31171 | (fluoride or fluor\$3 or fluorocarbon or fluoro-carbon or carbon) near5 (film or layer or dielectric or di-electric or di electric) same (void or space or hole or well) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/02 12:01 |
| S26 | 579 | S24 and S25 | US-PGPUB; USPAT; USOCR | OR | ON | 2009/04/02 12:01 |
| S27 | 2 | \$22 and \$26 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2009/04/02 12:01 |
| S28 | 6 | ("5900290" "6005291" "6071797" "6091081" "6215087").PN. OR ("6419985").URPN. | US-PGPUB; USPAT; USOOR | ADJ | ON | 2009/04/02 12:02 |
| S29 | 2 | ("5525447" "6121162").PN. OR ("6531409").URPN. | US-PGPUB; USPAT; USOOR | ADJ | ON | 2009/04/02 12:03 |
| S30 | 34 | ("6215087").URPN. | USPAT | ADJ | ON | 2009/04/02 12:08 |
| S31 | 149 | (((carbon adj3 fluoride) adj3 gas) or fluorocarbon adj3 film) same (induct\$3 or dielectric or di electric or di-electric) | USPAT | ADJ | ON | 2009/04/02 12:15 |
| S32 | 2 | S22 and S31 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/02 12:15 |

| S33 | 0 | (((carbon adj3 fluoride) adj3 gas) or fluorocarbon adj3 film) same (induct\$3 adj3 capacity) | USPAT | ADJ | ON | 2009/04/02 12:18 |
|-----|----------|---|---|-----|----|---------------------|
| S34 | 0 | (((carbon adj3 fluoride) adj3 gas) or fluorocarbon adj3 (film or layer)) same (induct\$3 adj3 capacity) | USPAT | ADJ | ON | 2009/04/02 12:19 |
| S35 | 34471 | 438/400-404,584-597,622- 624,637,672- 675,700,733,734,758-763,778- 780.ccls. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/02 12:30 |
| S36 | 9 | ("20040006249" "20040161946" "20040175501" "20050176230" "20060040507" "20060264059" "6429518" "6524963" "6593246"),PN. | US-PGPUB; USPAT; USOCR | ADJ | ON | 2009/04/02 12:41 |
| S37 | 108495 | (induct\$3 or deduct\$3 or causat \$3 or insulat\$3 or (low\$3 adj3 (dielectric or di-electric or di- electric))) near5 (constant or capacit\$3) same (less or low \$3) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/04 20:59 |
| S38 | 29211485 | @ad<"20040722" or @rlad<"20040722" | US PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/04 21:00 |
| S39 | 2442 | (first or second or third) near3 (fluoride or fluor\$3 or fluorocarbon or fluoro-carbon or carbon) near5 (substrate or wafer or semiconductor) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/04 21:00 |
| S40 | 31171 | (fluoride or fluor\$3 or fluorocarbon or fluoro-carbon or carbon) near5 (film or layer or dielectric or di-electric or di electric) same (void or space or hole or well) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/04 21:00 |
| S41 | 579 | S39 and S40 | US-PGPUB; USPAT; USOCR | OR | ON | 2009/04/04 21:00 |
| S42 | 447 | S41 and S38 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB | ADJ | ON | 2009/04/04 21:01 |

| S43 | 106 | S37 and S42 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/04 21:01 |
|-----|-------|---|---|-----|----|---------------------|
| S44 | 2442 | (first or second or third) near3 (fluoride or fluor\$3 or fluorocarbon or fluoro-carbon or carbon) near5 (substrate or wafer or semiconductor) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/04 21:02 |
| S45 | 31171 | (fluoride or fluor\$3 or fluorocarbon or fluoro-carbon or carbon) near5 (film or layer or dielectric or di-electric or di electric) same (void or space or hole or well) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/04 21:02 |
| S46 | 579 | S44 and S45 | US-PGPUB; USPAT; USOOR | OR | ON | 2009/04/04 21:02 |
| S47 | 106 | S43 and S46 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/04 21:02 |
| S48 | 14 | ((carbon near3 fluorocarbon) adj3 (film or gas or layer)) near5 (substrate or wafer or semiconductor) | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/04 21:03 |
| S49 | 0 | S48 and S47 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/04 21:03 |
| S50 | 34471 | 438/400-404,584-597,622- 624,637,672- 675,700,733,734,758-763,778- 780.ccls. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/04 21:04 |
| S51 | 35 | S50 and S47 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/04 21:04 |
| S52 | 0 | \$51 and (((carbon near3 fluorocarbon) adj3 (film or gas or layer)) same (substrate or wafer or semiconductor)) | US-PGPUB; USPAT; USOOR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/04/04 21:05 |

| S53 | 0 | S51 and ((carbon near3 | US-PGPUB; | ADJ | ON | 2009/04/04 |
|-----|---|---------------------------------|---------------|-----|----|------------|
| | | fluorocarbon) adj3 (film or gas | USPAT; USOCR; | | | 21:05 |
| | | or layer)) | FPRS; EPO; | | | |
| 1 | | | JPO; | | | |
| | | | DERWENT; | | | |
| | | | IBM_TDB | | | |
| | | | | | | |

EAST Search History (Interference)

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9/14/2009 1:11:23 AM

C:\ Documents and Settings\ amustapha\ My Documents\ EAST\ Workspaces\ 10_536774 (Fluorocarbon film and method for forming same).wsp